

MC14532B

8-Bit Priority Encoder

The MC14532B is constructed with complementary MOS (CMOS) enhancement mode devices. The primary function of a priority encoder is to provide a binary address for the active input with the highest priority. Eight data inputs (D0 thru D7) and an enable input (E_{in}) are provided. Five outputs are available, three are address outputs (Q0 thru Q2), one group select (GS) and one enable output (E_{out}).

Features

- Diode Protection on All Inputs
- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- Capable of Driving Two Low-Power TTL Loads or One Low-Power Schottky TTL Load over the Rated Temperature Range
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- This Device is Pb-Free and is RoHS Compliant

MAXIMUM RATINGS (Voltages Referenced to V_{SS})

| Rating | Symbol | Value | Unit |
|---|----------------------|------------------------|------|
| DC Supply Voltage Range | V_{DD} | -0.5 to +18.0 | V |
| Input or Output Voltage Range (DC or Transient) | V_{in} , V_{out} | -0.5 to $V_{DD} + 0.5$ | V |
| Input or Output Current (DC or Transient) per Pin | I_{in} , I_{out} | ± 10 | mA |
| Power Dissipation, per Package (Note 1) | P_D | 500 | mW |
| Ambient Temperature Range | T_A | -55 to +125 | °C |
| Storage Temperature Range | T_{stg} | -65 to +150 | °C |
| Lead Temperature (8 Sec Soldering) | T_L | 260 | °C |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Temperature Derating: "D/DW" Package: -7.0 mW/°C From 65°C To 125°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range $V_{SS} \leq (V_{in} \text{ or } V_{out}) \leq V_{DD}$.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either V_{SS} or V_{DD}). Unused outputs must be left open.

TRUTH TABLE

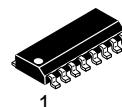
| Input | | | | | | | | | Output | | | | |
|----------|----|----|----|----|----|----|----|----|--------|----|----|----|-----------|
| E_{in} | D7 | D6 | D5 | D4 | D3 | D2 | D1 | D0 | GS | Q2 | Q1 | Q0 | E_{out} |
| 0 | X | X | X | X | X | X | X | X | 0 | 0 | 0 | 0 | 0 |
| 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 1 |
| 1 | 1 | X | X | X | X | X | X | X | 1 | 1 | 1 | 1 | 0 |
| 1 | 0 | 1 | X | X | X | X | X | X | 1 | 1 | 1 | 0 | 0 |
| 1 | 0 | 0 | 1 | X | X | X | X | X | 1 | 1 | 0 | 1 | 0 |
| 1 | 0 | 0 | 0 | 1 | X | X | X | X | 1 | 1 | 0 | 0 | 0 |
| 1 | 0 | 0 | 0 | 0 | 1 | X | X | X | 1 | 0 | 1 | 1 | 0 |
| 1 | 0 | 0 | 0 | 0 | 0 | 1 | X | X | 1 | 0 | 1 | 0 | 0 |
| 1 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | X | 1 | 0 | 0 | 1 | 0 |
| 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 1 | 0 | 0 | 0 | 0 |

X = Don't Care



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SOIC-16
D SUFFIX
CASE 751B

PIN ASSIGNMENT

| | | | |
|----------|---|----|-----------|
| D4 | 1 | 16 | V_{DD} |
| D5 | 2 | 15 | E_{out} |
| D6 | 3 | 14 | GS |
| D7 | 4 | 13 | D3 |
| E_{in} | 5 | 12 | D2 |
| Q2 | 6 | 11 | D1 |
| Q1 | 7 | 10 | D0 |
| V_{SS} | 8 | 9 | Q0 |

MARKING DIAGRAM



A = Assembly Location
WL = Wafer Lot
YY, Y = Year
WW = Work Week
G = Pb-Free Package

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

MC14532B

ORDERING INFORMATION

| Device | Package | Shipping† |
|----------------|----------------------|--------------------|
| MC14532BDG | SOIC–16 (Pb–Free) | 48 Units / Rail |
| MC14532BDR2G | SOIC–16 (Pb–Free) | 2500 / Tape & Reel |
| NLV14532BDR2G* | SOIC–16 (Pb–Free) | 2500 / Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP Capable.

ELECTRICAL CHARACTERISTICS (Voltages Referenced to V_{SS})

| Characteristic | Symbol | V _{DD} Vdc | – 55° C | | 25° C | | | 125° C | | Unit |
|---|---------------------------|------------------------|--|------|-------|-----------------|------|--------|------|------|
| | | | Min | Max | Min | Typ (Note 2) | Max | Min | Max | |
| Output Voltage V _{in} = V _{DD} or 0 V _{in} = 0 or V _{DD} | V _{OL} | 5.0 | – | 0.05 | – | 0 | 0.05 | – | 0.05 | Vdc |
| | | 10 | – | 0.05 | – | 0 | 0.05 | – | 0.05 | |
| | | 15 | – | 0.05 | – | 0 | 0.05 | – | 0.05 | |
| | V _{OH} | 5.0 | 4.95 | – | 4.95 | 5.0 | – | 4.95 | – | Vdc |
| | | 10 | 9.95 | – | 9.95 | 10 | – | 9.95 | – | |
| | | 15 | 14.95 | – | 14.95 | 15 | – | 14.95 | – | |
| Input Voltage (V _O = 4.5 or 0.5 Vdc) (V _O = 9.0 or 1.0 Vdc) (V _O = 13.5 or 1.5 Vdc) (V _O = 0.5 or 4.5 Vdc) (V _O = 1.0 or 9.0 Vdc) (V _O = 1.5 or 13.5 Vdc) | V _{IL} | 5.0 | – | 1.5 | – | 2.25 | 1.5 | – | 1.5 | Vdc |
| | | 10 | – | 3.0 | – | 4.50 | 3.0 | – | 3.0 | |
| | | 15 | – | 4.0 | – | 6.75 | 4.0 | – | 4.0 | |
| | V _{IH} | 5.0 | 3.5 | – | 3.5 | 2.75 | – | 3.5 | – | Vdc |
| | | 10 | 7.0 | – | 7.0 | 5.50 | – | 7.0 | – | |
| | | 15 | 11 | – | 11 | 8.25 | – | 11 | – | |
| Output Drive Current (V _{OH} = 2.5 Vdc) (V _{OH} = 4.6 Vdc) (V _{OH} = 9.5 Vdc) (V _{OH} = 13.5 Vdc) | Source I _{OH} | 5.0 | –3.0 | – | –2.4 | –4.2 | – | –1.7 | – | mAdc |
| | | 5.0 | –0.64 | – | –0.51 | –0.88 | – | –0.36 | – | |
| | | 10 | –1.6 | – | –1.3 | –2.25 | – | –0.9 | – | |
| | | 15 | –4.2 | – | –3.4 | –8.8 | – | –2.4 | – | |
| (V _{OL} = 0.4 Vdc) (V _{OL} = 0.5 Vdc) (V _{OL} = 1.5 Vdc) | Sink I _{OL} | 5.0 | 0.64 | – | 0.51 | 0.88 | – | 0.36 | – | mAdc |
| | | 10 | 1.6 | – | 1.3 | 2.25 | – | 0.9 | – | |
| | | 15 | 4.2 | – | 3.4 | 8.8 | – | 2.4 | – | |
| Input Current | I _{in} | 15 | – | ±0.1 | – | ±0.00001 | ±0.1 | – | ±1.0 | μAdc |
| Input Capacitance (V _{in} = 0) | C _{in} | – | – | – | – | 5.0 | 7.5 | – | – | pF |
| Quiescent Current (Per Package) | I _{DD} | 5.0 | – | 5.0 | – | 0.005 | 5.0 | – | 150 | μAdc |
| | | 10 | – | 10 | – | 0.010 | 10 | – | 300 | |
| | | 15 | – | 20 | – | 0.015 | 20 | – | 600 | |
| Total Supply Current (Notes 3, 4) (Dynamic plus Quiescent, Per Package) (C _L = 50 pF on all outputs, all buffers switching) | I _T | 5.0 10 15 | I _T = (1.74 μA/kHz) f + I _{DD} I _T = (3.65 μA/kHz) f + I _{DD} I _T = (5.73 μA/kHz) f + I _{DD} | | | | | | | μAdc |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Data labelled “Typ” is not to be used for design purposes but is intended as an indication of the IC’s potential performance.

3. The formulas given are for the typical characteristics only at 25°C.

4. To calculate total supply current at loads other than 50 pF:

$$I_T(C_L) = I_T(50 \text{ pF}) + (C_L - 50) V f k$$

where: I_T is in μA (per package), C_L in pF, V = (V_{DD} – V_{SS}) in volts, f in kHz is input frequency, and k = 0.005.

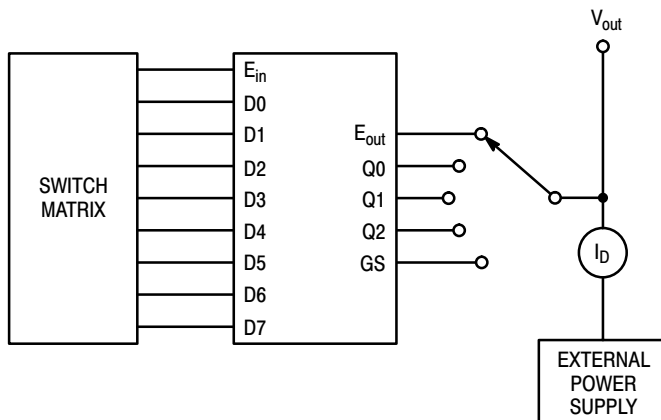
MC14532B

SWITCHING CHARACTERISTICS ($C_L = 50 \text{ pF}$, $T_A = 25^\circ\text{C}$) (Note 5)

| Characteristic | Symbol | V_{DD} | Min | Typ (Note 6) | Max | Unit |
|--|--------------------|-----------------|-------------|-------------------|-------------------|------|
| Output Rise and Fall Time $t_{TLH}, t_{THL} = (1.5 \text{ ns/pF}) C_L + 25 \text{ ns}$ $t_{TLH}, t_{THL} = (0.75 \text{ ns/pF}) C_L + 12.5 \text{ ns}$ $t_{TLH}, t_{THL} = (0.55 \text{ ns/pF}) C_L + 9.5 \text{ ns}$ | t_{TLH}, t_{THL} | 5.0 10 15 | — — — | 100 50 40 | 200 100 80 | ns |
| Propagation Delay Time — E_{in} to E_{out} $t_{PLH}, t_{PHL} = (1.7 \text{ ns/pF}) C_L + 120 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.66 \text{ ns/pF}) C_L + 77 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.5 \text{ ns/pF}) C_L + 55 \text{ ns}$ | t_{PLH}, t_{PHL} | 5.0 10 15 | — — — | 205 110 80 | 410 220 160 | ns |
| Propagation Delay Time — E_{in} to GS $t_{PLH}, t_{PHL} = (1.7 \text{ ns/pF}) C_L + 90 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.66 \text{ ns/pF}) C_L + 57 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.5 \text{ ns/pF}) C_L + 40 \text{ ns}$ | t_{PLH}, t_{PHL} | 5.0 10 15 | — — — | 175 90 65 | 350 180 130 | ns |
| Propagation Delay Time — E_{in} to Q_n $t_{PLH}, t_{PHL} = (1.7 \text{ ns/pF}) C_L + 195 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.66 \text{ ns/pF}) C_L + 107 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.5 \text{ ns/pF}) C_L + 75 \text{ ns}$ | t_{PLH}, t_{PHL} | 5.0 10 15 | — — — | 280 140 100 | 560 280 200 | ns |
| Propagation Delay Time — D_n to Q_n $t_{PLH}, t_{PHL} = (1.7 \text{ ns/pF}) C_L + 265 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.66 \text{ ns/pF}) C_L + 137 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.5 \text{ ns/pF}) C_L + 85 \text{ ns}$ | t_{PLH}, t_{PHL} | 5.0 10 15 | — — — | 300 170 110 | 600 340 220 | ns |
| Propagation Delay Time — D_n to GS $t_{PLH}, t_{PHL} = (1.7 \text{ ns/pF}) C_L + 195 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.66 \text{ ns/pF}) C_L + 107 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.5 \text{ ns/pF}) C_L + 75 \text{ ns}$ | t_{PLH}, t_{PHL} | 5.0 10 15 | — — — | 280 140 100 | 560 280 200 | ns |

5. The formulas given are for the typical characteristics only at 25°C .

6. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.



| Output Under Test | $V_{GS} = V_{DD}$ $V_{DS} = V_{out}$ Sink Current | | $V_{GS} = -V_{DD}$ $V_{DS} = V_{out} - V_{DD}$ Source Current | | | |
|-------------------|---|----------|---|----|----------|--|
| | D0 thru D7 | E_{in} | D0 thru D6 | D7 | E_{in} | |
| E_{out} | X | 0 | 0 | 0 | 1 | |
| Q0 | X | 0 | 0 | 1 | 1 | |
| Q1 | X | 0 | 0 | 1 | 1 | |
| Q2 | X | 0 | 0 | 1 | 1 | |
| GS | X | 0 | 0 | 1 | 1 | |

Figure 1. Typical Sink and Source Current Characteristics

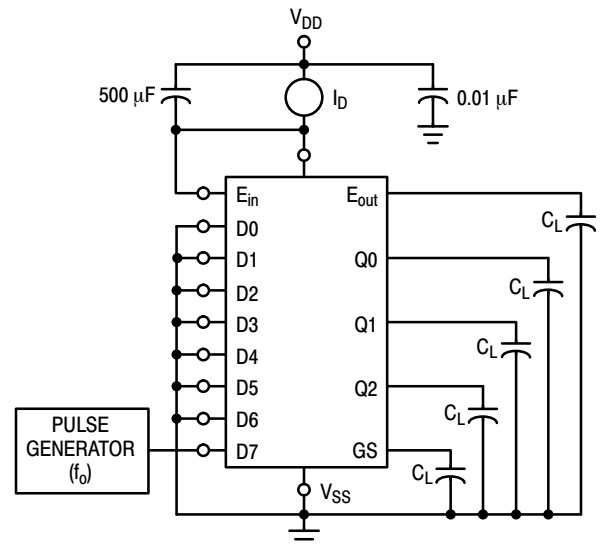


Figure 2. Typical Power Dissipation Test Circuit

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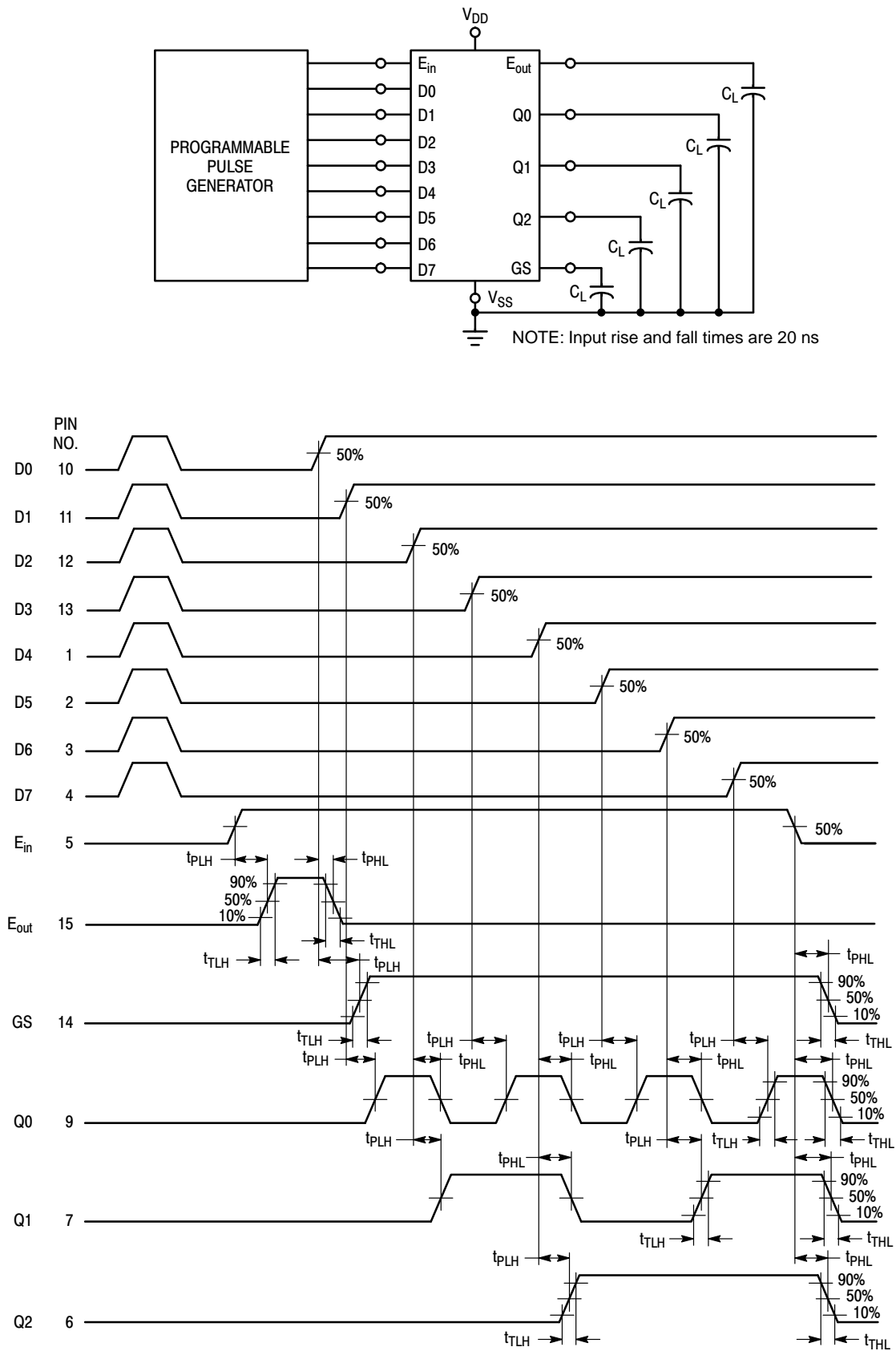


Figure 3. AC Test Circuit and Waveforms

MC14532B

LOGIC EQUATIONS

$$E_{out} = E_{in} \cdot \bar{D0} \cdot \bar{D1} \cdot \bar{D2} \cdot \bar{D3} \cdot \bar{D4} \cdot \bar{D5} \cdot \bar{D6} \cdot \bar{D7}$$

$$Q0 = E_{in} \cdot (D1 \cdot \bar{D2} \cdot \bar{D4} \cdot \bar{D6} + D3 \cdot \bar{D4} \cdot \bar{D6} + D5 \cdot \bar{D6} + D7)$$

$$Q1 = E_{in} \cdot (D2 \cdot \bar{D4} \cdot \bar{D5} + D3 \cdot \bar{D4} \cdot \bar{D5} + D6 + D7)$$

$$Q2 = E_{in} \cdot (D4 + D5 + D6 + D7)$$

$$GS = E_{in} \cdot (D0 + D1 + D2 + D3 + D4 + D5 + D6 + D7)$$

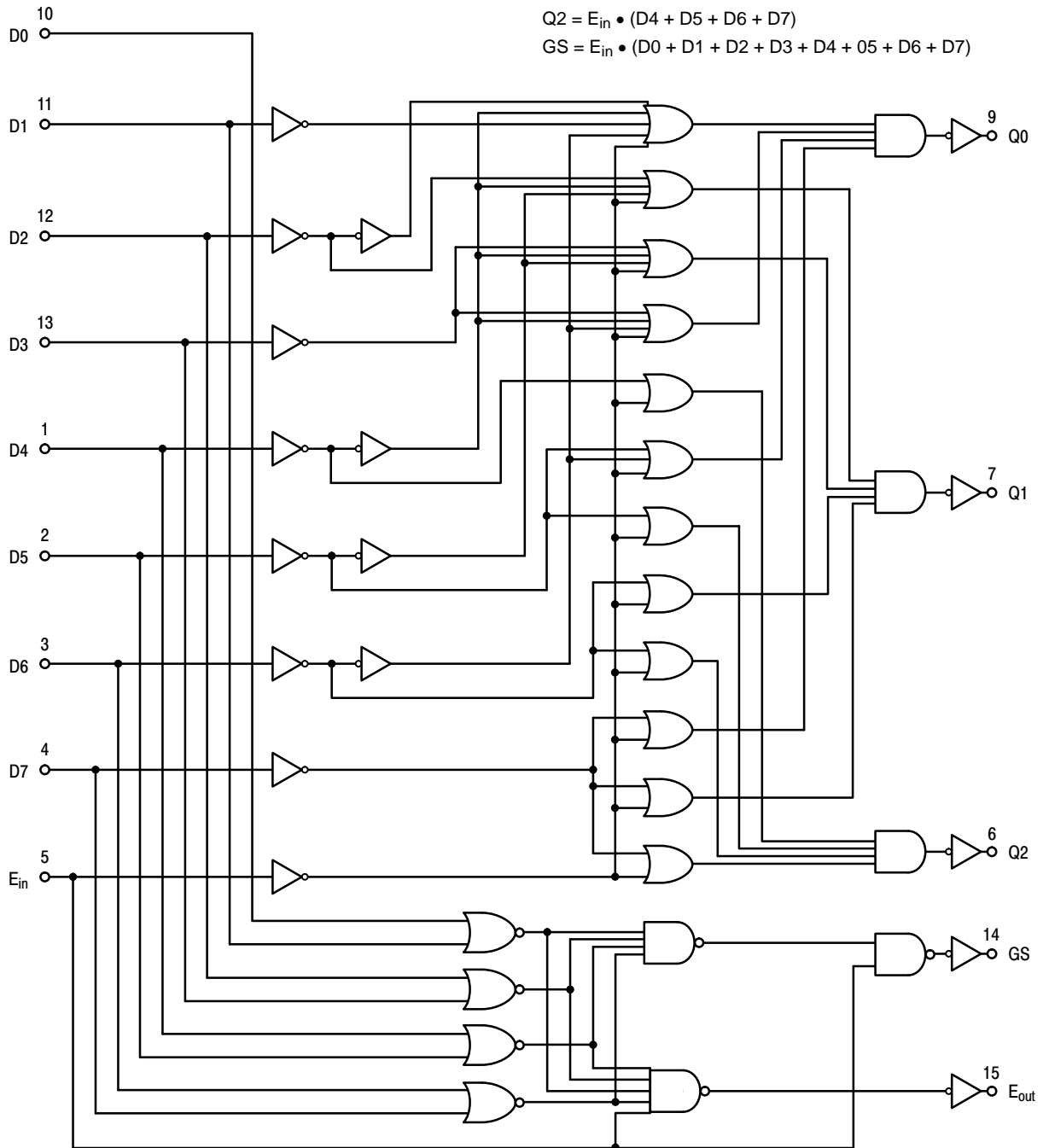
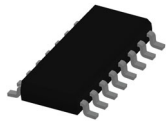


Figure 4. Logic Diagram
(Positive Logic)

MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

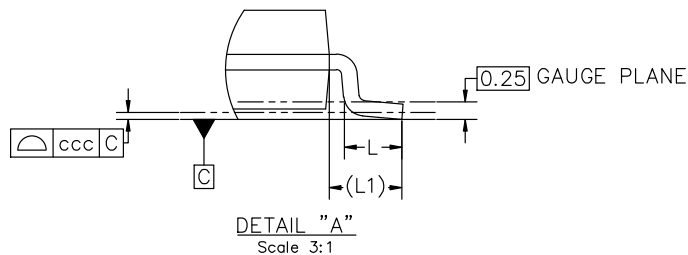
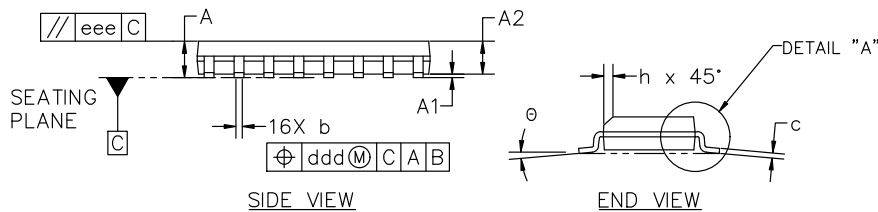
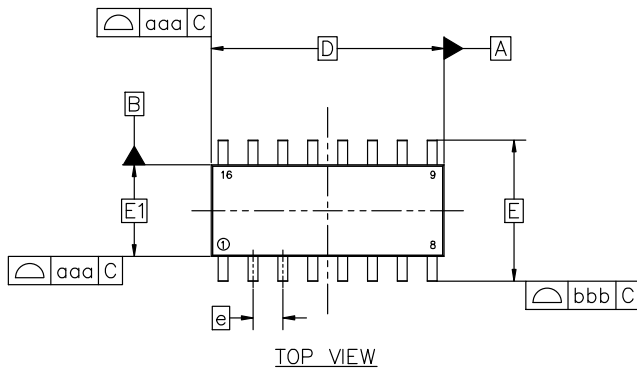


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CASE 751B
ISSUE L

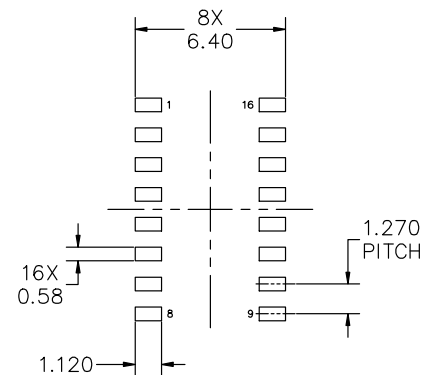
DATE 29 MAY 2024

NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
2. DIMENSION IN MILLIMETERS. ANGLE IN DEGREES.
3. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15mm PER SIDE.
5. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127mm TOTAL IN EXCESS OF THE b DIMENSION AT MAXIMUM MATERIAL CONDITION.



| MILLIMETERS | | | |
|--------------------------------|----------|------|------|
| DIM | MIN | NOM | MAX |
| A | 1.35 | 1.55 | 1.75 |
| A1 | 0.00 | 0.05 | 0.10 |
| A2 | 1.35 | 1.50 | 1.65 |
| b | 0.35 | 0.42 | 0.49 |
| c | 0.19 | 0.22 | 0.25 |
| D | 9.90 BSC | | |
| E | 6.00 BSC | | |
| E1 | 3.90 BSC | | |
| e | 1.27 BSC | | |
| h | 0.25 | --- | 0.50 |
| L | 0.40 | 0.83 | 1.25 |
| L1 | 1.05 REF | | |
| θ | 0° | --- | 7° |
| TOLERANCE OF FORM AND POSITION | | | |
| aaa | 0.10 | | |
| bbb | 0.20 | | |
| ccc | 0.10 | | |
| ddd | 0.25 | | |
| eee | 0.10 | | |



RECOMMENDED MOUNTING FOOTPRINT

*FOR ADDITIONAL INFORMATION ON OUR PB-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE onsemi SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERM/D

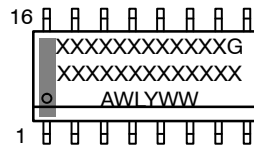
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SOIC-16 9.90x3.90x1.50 1.27P
CASE 751B
ISSUE L

DATE 29 MAY 2024

GENERIC
MARKING DIAGRAM*



XXXXXX = Specific Device Code
A = Assembly Location
WL = Wafer Lot
Y = Year
WW = Work Week
G = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

| | | | |
|--|--|--|--|
| STYLE 1: PIN 1. COLLECTOR 2. BASE 3. EMITTER 4. NO CONNECTION 5. EMITTER 6. BASE 7. COLLECTOR 8. COLLECTOR 9. BASE 10. EMITTER 11. NO CONNECTION 12. EMITTER 13. BASE 14. COLLECTOR 15. EMITTER 16. COLLECTOR | STYLE 2: PIN 1. CATHODE 2. ANODE 3. NO CONNECTION 4. CATHODE 5. CATHODE 6. NO CONNECTION 7. ANODE 8. CATHODE 9. CATHODE 10. ANODE 11. NO CONNECTION 12. CATHODE 13. CATHODE 14. NO CONNECTION 15. ANODE 16. CATHODE | STYLE 3: PIN 1. COLLECTOR, DYE #1 2. BASE, #1 3. EMITTER, #1 4. COLLECTOR, #1 5. COLLECTOR, #2 6. BASE, #2 7. EMITTER, #2 8. COLLECTOR, #2 9. COLLECTOR, #3 10. BASE, #3 11. EMITTER, #3 12. COLLECTOR, #3 13. COLLECTOR, #4 14. BASE, #4 15. EMITTER, #4 16. COLLECTOR, #4 | STYLE 4: PIN 1. COLLECTOR, DYE #1 2. COLLECTOR, #1 3. COLLECTOR, #2 4. COLLECTOR, #2 5. COLLECTOR, #3 6. COLLECTOR, #3 7. COLLECTOR, #4 8. COLLECTOR, #4 9. BASE, #4 10. EMITTER, #4 11. BASE, #3 12. EMITTER, #3 13. BASE, #2 14. EMITTER, #2 15. BASE, #1 16. EMITTER, #1 |
| STYLE 5: PIN 1. DRAIN, DYE #1 2. DRAIN, #1 3. DRAIN, #2 4. DRAIN, #2 5. DRAIN, #3 6. DRAIN, #3 7. DRAIN, #4 8. DRAIN, #4 9. GATE, #4 10. SOURCE, #4 11. GATE, #3 12. SOURCE, #3 13. GATE, #2 14. SOURCE, #2 15. GATE, #1 16. SOURCE, #1 | STYLE 6: PIN 1. CATHODE 2. CATHODE 3. CATHODE 4. CATHODE 5. CATHODE 6. CATHODE 7. CATHODE 8. CATHODE 9. ANODE 10. ANODE 11. ANODE 12. ANODE 13. ANODE 14. ANODE 15. ANODE 16. ANODE | STYLE 7: PIN 1. SOURCE N-CH 2. COMMON DRAIN (OUTPUT) 3. COMMON DRAIN (OUTPUT) 4. GATE P-CH 5. COMMON DRAIN (OUTPUT) 6. COMMON DRAIN (OUTPUT) 7. COMMON DRAIN (OUTPUT) 8. SOURCE P-CH 9. SOURCE P-CH 10. COMMON DRAIN (OUTPUT) 11. COMMON DRAIN (OUTPUT) 12. COMMON DRAIN (OUTPUT) 13. GATE N-CH 14. COMMON DRAIN (OUTPUT) 15. COMMON DRAIN (OUTPUT) 16. SOURCE N-CH | |

| | | |
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